

BGY585A

550 MHz, 18.2 dB gain push-pull amplifier

Rev. 05 — 24 January 2005

Product data sheet



1.1 General description

Hybrid amplifier module for CATV systems operating over a frequency range of 40 MHz to 550 MHz at a voltage supply of 24 V (DC). Intended for use as a final amplifier.

1.2 Features

- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals

1.3 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G_p	power gain	f = 50 MHz	17.7	-	18.7	dB
		f = 550 MHz	18.8	-	20	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	-	220	240	mA

2. Pinning information

Table 2: Pinning

Table 2:	Pinning		
Pin	Description	Simplified outline	Symbol
1	input		
2	common	123 5 789	5
3	common		$\frac{1}{2}$
5	+V _B	Side view	2378
7	common		2 3 7 8 sym095
8	common		
9	output		





3. Ordering information

Table 3: Ordering information

Туре	Package	ge				
number	Name	Description	Version			
BGY585A	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J			

4. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Vi	RF input voltage		-	65	dBmV
T _{stg}	storage temperature		-40	+100	°C
T _{case}	case operating temperature		-20	+100	°C

5. Characteristics

Table 5: Characteristics $T_{case} = 30 \,^{\circ}C; Z_S = Z_L = 75 \,\Omega.$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Bandwidth	Bandwidth 40 MHz to 550 MHz						
Gp	power gain	f = 50 MHz	17.7	-	18.7	dB	
		f = 550 MHz	18.8	-	20	dB	
SL	slope cable equivalent	f = 40 MHz to 550 MHz	0.5	-	2	dB	
FL	flatness of frequency response	f = 40 MHz to 550 MHz	-	-	±0.2	dB	
S ₁₁	input return losses	f = 40 MHz to 80 MHz	20	-	-	dB	
		f = 80 MHz to 160 MHz	19	-	-	dB	
		f = 160 MHz to 550 MHz	18	-	-	dB	
s ₂₂	output return losses	f = 40 MHz to 80 MHz	20	-	-	dB	
		f = 80 MHz to 160 MHz	19	-	-	dB	
		f = 160 MHz to 550 MHz	18	-	-	dB	
СТВ	composite triple beat	77 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 547.25 MHz	-	-	– 59	dB	
X_{mod}	cross modulation	77 channels flat; $V_0 = 44 \text{ dBmV}$; measured at 55.25 MHz	-	-	-62	dB	
CSO	composite second order distortion	77 channels flat; $V_0 = 44$ dBmV; measured at 548.5 MHz	-	-	– 59	dB	
d_2	second order distortion		<u>[1]</u> -	-	-72	dB	
V _o	output voltage	$d_{im} = -60 \text{ dB}$	^[2] 61.5	-	-	dBmV	
F	noise figure	f = 550 MHz	-	-	8	dB	
I _{tot}	total current consumption (DC)	V _B = 24 V	[3] -	220	240	mA	

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 Table 5:
 Characteristics ...continued

 $T_{case} = 30 \,^{\circ}C; Z_S = Z_L = 75 \,\Omega.$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Bandwidth	40 MHz to 450 MHz					
Gp	power gain	f = 50 MHz	17.7	-	18.7	dB
		f = 450 MHz	18.6	-	19.8	dB
SL	slope cable equivalent	f = 40 MHz to 450 MHz	0.5	-	1.8	dB
FL	flatness of frequency response	f = 40 MHz to 450 MHz	-	-	±0.2	dB
S ₁₁	input return losses	f = 40 MHz to 80 MHz	20	-	-	dB
		f = 80 MHz to 160 MHz	19	-	-	dB
		f = 160 MHz to 450 MHz	18	-	-	dB
\$ ₂₂	output return losses	f = 40 MHz to 80 MHz	20	-	-	dB
		f = 80 MHz to 160 MHz	19	-	-	dB
		f = 160 MHz to 450 MHz	18	-	-	dB
СТВ	composite triple beat	60 channels flat; $V_0 = 46 \text{ dBmV}$; measured at 445.25 MHz	-	-	- 61	dB
X _{mod}	cross modulation	60 channels flat; $V_0 = 46$ dBmV; measured at 55.25 MHz	-	-	- 61	dB
CSO	composite second order distortion	60 channels flat; $V_0 = 46 \text{ dBmV}$; measured at 446.5 MHz	-	-	- 61	dB
d ₂	second order distortion		[4] _	-	-75	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$	[<u>5]</u> 64	-	-	dBmV
F	noise figure	f = 450 MHz	-	-	7	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	[3] -	220	240	mA

^[1] $f_p = 55.25$ MHz; $V_p = 44$ dBmV; $f_q = 493.25$ MHz; $V_q = 44$ dBmV; measured at $f_p + f_q = 548.5$ MHz.

^[2] Measured according to DIN45004B; f_p = 540.25 MHz; V_p = V_o ; f_q = 547.25 MHz; V_q = V_o -6 dB; f_r = 549.25 MHz; V_r = V_o -6 dB; measured at f_p + f_q - f_r = 538.25 MHz.

^[3] The module normally operates at $V_B = 24 \text{ V}$, but is able to withstand supply transients up to 30 V.

^[4] $f_p = 55.25$ MHz; $V_p = 46$ dBmV; $f_q = 391.25$ MHz; $V_q = 46$ dBmV; measured at $f_p + f_q = 446.5$ MHz.

^[5] Measured according to DIN45004B; f_p = 440.25 MHz; V_p = V_o ; f_q = 447.25 MHz; V_q = V_o -6 dB; f_r = 449.25 MHz; V_r = V_o -6 dB; measured at f_p + f_q - f_r = 438.25 MHz.

6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

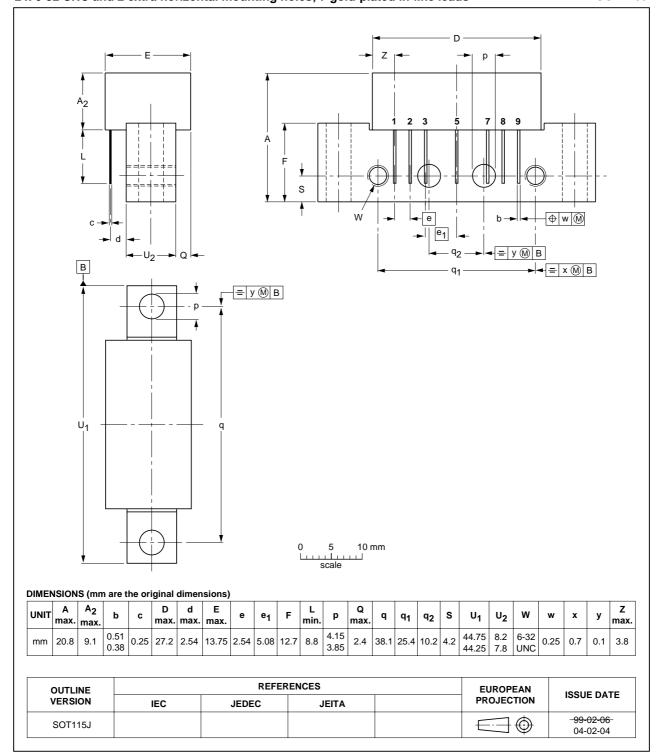


Fig 1. Package outline SOT115J

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7. Revision history

Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BGY585A_5	20050124	Product data sheet	-	9397 750 14432	BGY585A_4
Modifications:		t of this data sheet has b n standard of Philips Sen		comply with the nev	v presentation and
BGY585A_4	20011018	Product specification	-	9397 750 08802	BGY585A_3
BGY585A_3	19990326	Product specification	-	9397 750 06341	BGY585A_2

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